

EE105 Lab Experiments

## Report 6: Biasing Circuitry

Name:

Lab Section:

### 1 Lab Questions

3.1.3 What is  $R_C$  when  $V_{OUT} = 650$  mV?

$R_C =$

3.1.4 Roughly sketch  $I_C$  vs.  $V_{OUT}$  for the transistor and for the resistor, showing the fixed point solution for  $V_{OUT}$ . How would we adjust the resistor to increase  $V_{OUT}$ ?

3.1.5 Will the voltage source become better or worse (better as defined by being closer to an ideal source) as the resistor decreases? Why?

3.1.6 Find the output impedance of the voltage source.

$R_{out} =$

3.1.7 Now, suppose you want to make your voltage source output 1.3 V. Clearly, putting 1.3 V on  $V_{BE}$  of the diode connected BJT is not a good idea (please, don't even try). Draw a circuit topology to achieve this voltage without requiring a BJT to have an extremely high  $V_{BE}$ .

3.2.2 Short circuit current:

$$I_{OUT} =$$

3.2.3 Find  $R_{out}$  in terms of the small-signal characteristics.

$$\text{Theoretical } R_{out} =$$

3.2.4 What happens to the output impedance as  $V_{OUT}$  nears 5 V?

3.2.5 Output impedance at  $V_{OUT} = 2.5$  V

$$\text{Measured } R_{out} =$$

3.2.6–8 Transistors in parallel with  $V_{OUT} = 2.5$  V:

$$I_{OUT} =$$

$$R_{out} =$$

Explain the effect of the second transistor on the output impedance.

3.3.2–6 Properties of the CE amp with current mirror:

$$V_{IN} =$$

$$A_v =$$

$$I_{C2} =$$

$$I_{C3} =$$

$$R_{in} =$$

$$R_{out} =$$

3.3.7 How do the impedances and gain compare with a common emitter biased with a resistor instead?

3.3.8 Explain this effect using what you know about BJT temperature effects. How may this be an advantage of BJT biasing over resistive biasing?